



#### 250V N-CHANNEL ENHANCEMENT MODE MOSFET

### **Product Summary**

BV <sub>DSS</sub>	Max R <sub>DS(ON)</sub>	Max I <sub>D</sub> T <sub>A</sub> = +25°C
250V	8.5Ω @ V <sub>GS</sub> = 10V	230mA

### **Description and Applications**

This 250V enhancement mode N-channel MOSFET provides users with a competitive specification. It offers efficient power handling capability, high impedance and is free from thermal runaway and thermally induced secondary breakdowns. Applications benefiting from this device include a variety of telecom and general high-voltage circuits.

SOT89 and SOT223 versions are also available.

- Earth recall and dialing switches
- Electronic hook switches
- High-voltage power MOSFET drivers
- Telecom call routers
- Solid-state relays

### **Features and Benefits**

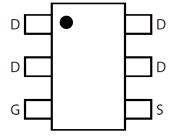
- High Voltage
- Low On-Resistance
- Fast Switching Speed
- Low Threshold
- Low Gate Drive
- Complementary P-Channel Type ZVP4525E6
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/guality/product-definitions/

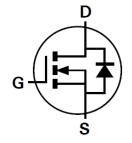
#### **Mechanical Data**

- Package: SOT26
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.015 grams (Approximate)









Top View

**Device Symbol** 

April 2024

#### Ordering Information (Note 4)

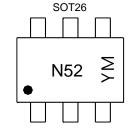
Part Number	Package	Reel Size (inch)	Tape Width (mm)	Packing	
Part Number	Package	Reel Size (Ilicii)	rape widin (min)	Qty.	Carrier
ZVN4525E6TA	SOT26	7	8	3000	Reel
ZVN4525E6TC	SOT26	13	8	10,000	Reel

Pinout Top-View

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

## **Marking Information**



N52 = Product Type Marking Code YM = Date Code Marking Y or  $\overline{Y}$  = Year (ex: L = 2024) M or  $\overline{M}$  = Month (ex: 4 = April)

Date Code Kev

Year	2015	-	2024	2025	2026	2027	2028	2029	2030	2031	2032	2033
Code	С	-	L	М	N	Р	R	S	Т	U	V	W
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
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### **Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			VDSS	250	V
Gate-Source Voltage			V <sub>GS</sub>	±40	V
Continuous Drain Current VGS = 10V	1/ 401/	$T_A = +25$ °C (Note 5)	1-	230	A
	$T_A = +70^{\circ}C \text{ (Note 5)}$	- ID	183	mA mA	
Pulsed Drain Current (Note	7)		I <sub>DM</sub>	1.44	Α
Continuous Source Current (Body Diode)			Is	1.1	Α
Pulsed Source Current (Boo	dy Diode)		Ism	1.44	Α

# Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation at $T_A = +25^{\circ}C$ (Note 5) Linear Derating Factor	P <sub>D</sub>	1.1 8.8	W mW/°C
Junction to Ambient (Note 5)	R <sub>θ</sub> JA	113	°C/W
Junction to Ambient (Note 6)	RθJA	65	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

Notes: 5. For a device surface mounted on 25mm x 25mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions.

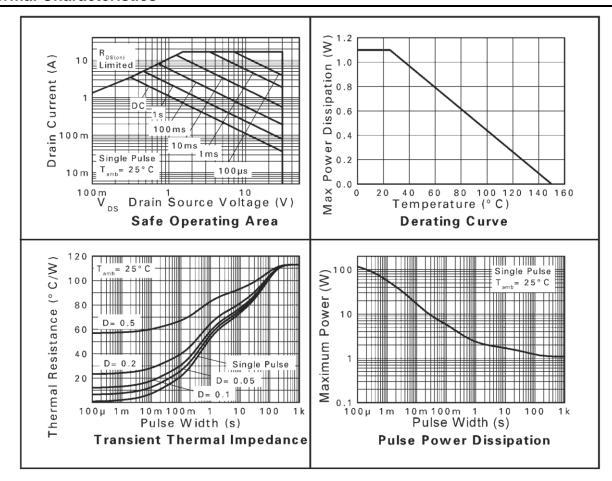
6. For a device surface mounted on FR4 PCB measured at  $t \le 5$  secs.

7. Repetitive rating - pulse width limited by maximum junction temperature. Refer to Transient Thermal.

#### **NB High Voltage Applications**

For high voltage applications, the appropriate industry sector guidelines should be considered with regards to voltage spacing between conductors.

### **Thermal Characteristics**





# **Electrical Characteristics** (@TA = +25°C, unless otherwise specified.)

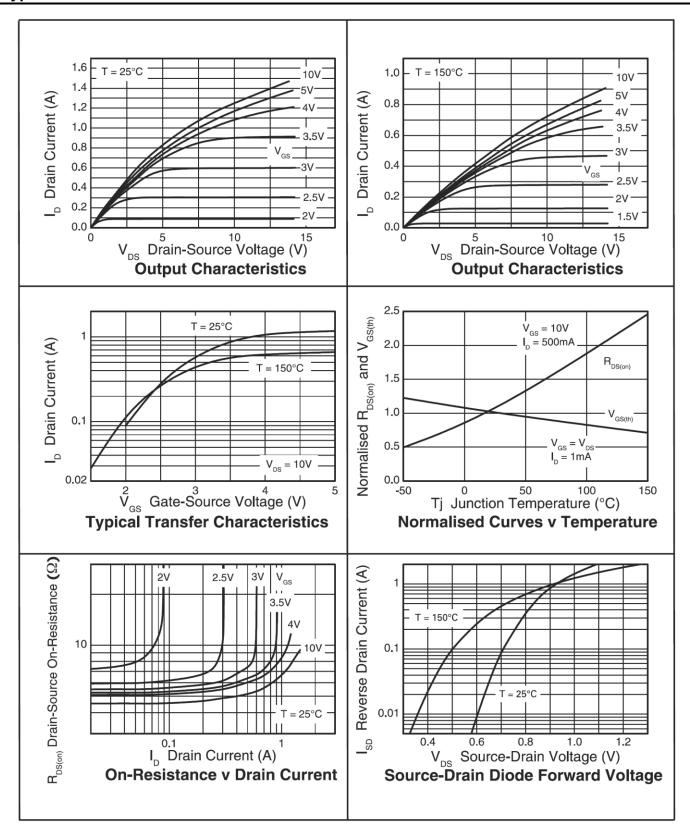
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS						
Drain-Source Breakdown Voltage	BVDSS	250	285		V	$I_D = 1mA$ , $V_{GS} = 0$
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	_	35	500	nA	$V_{DS} = 250V, V_{GS} = 0$
Gate-Body Leakage	Igss	_	±1	100	nA	$V_{GS} = \pm 40V, V_{DS} = 0$
ON CHARACTERISTICS						
Gate-Source Threshold Voltage	VGS(th)	8.0	1.4	1.8	V	$I_D = 1mA$ , $V_{DS} = V_{GS}$
			5.6	8.5		V <sub>G</sub> S = 10V, I <sub>D</sub> = 500mA
Static Drain-Source On-State Resistance (Note 8)	R <sub>DS(ON)</sub>	_	5.9	9.0	Ω	$V_{GS} = 4.5V, I_D = 360mA$
	, ,		6.4	9.5		V <sub>G</sub> S = 2.4V, I <sub>D</sub> = 20mA
Forward Transconductance (Note 10)		0.3	0.475		S	V <sub>DS</sub> = 10V, I <sub>D</sub> = 0.3A
Diode Forward Voltage (Note 8)	V <sub>SD</sub>		_	0.97	V	$T_J = +25$ °C, $I_S = 360$ mA, $V_{GS} = 0$
DYNAMIC CHARACTERISTICS (Notes 9 & 10)						
Input Capacitance	Ciss		72		pF	\\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \
Output Capacitance	Coss		11	_	pF	V <sub>DS</sub> = 25V, V <sub>GS</sub> = 0, - f = 1MHz
Reverse Transfer Capacitance	Crss	_	3.6	_	pF	
Total Gate Charge	Qg	_	2.6	3.65	nC	101/1/
Gate-Source Charge	Qgs	_	0.2	0.28	nC	Vgs = 10V, Vps = 25V,
Gate-Drain Charge	Qgd	_	0.5	0.7	nC	ID = 360mA (refer to test circuit)
Reverse-Recovery Time (Note 10)	trr	_	186	260	ns	T <sub>J</sub> = +25°C, I <sub>F</sub> = 360A,
Reverse-Recovery Charge (Note 10)	Qrr	_	34	48	nC	di/dt = 100A/µs
Turn-On Delay Time	td(on)	_	1.25	_	ns	
Turn-On Rise Time	tr		1.7	_	ns	$V_{DD} = 30V, V_{GS} = 10V,$
Turn-Off Delay Time	t <sub>d(off)</sub>		11.40	_	ns	$I_D = 360 \text{mA}, R_G = 50 \Omega$
Turn-Off Fall Time	tf		3.5	_	ns	(refer to test circuit)

Notes:

<sup>8.</sup> Measured under pulsed conditions. Width = 300µs. Duty cycle ≤ 2%.
9. Switching characteristics are independent of operating junction temperature.
10. For design aid only, not subject to production testing.

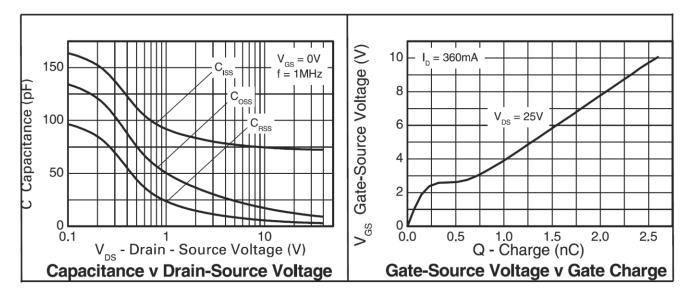


# **Typical Characteristics**

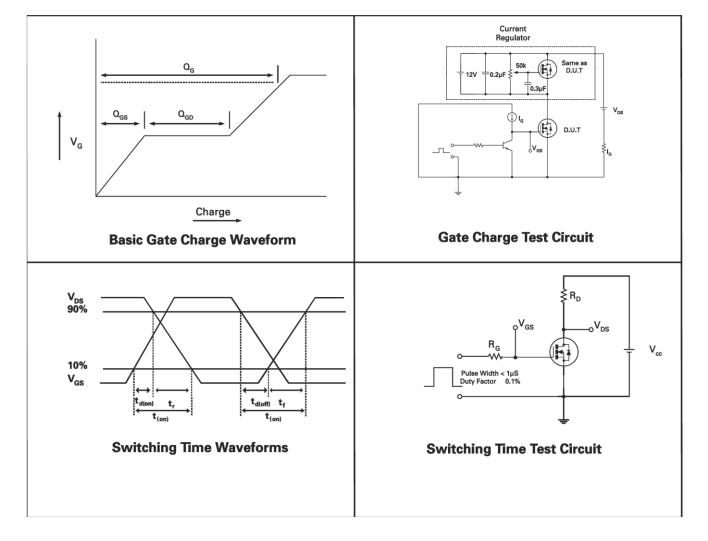




# Typical Characteristics (continued)



### **Test Circuits**

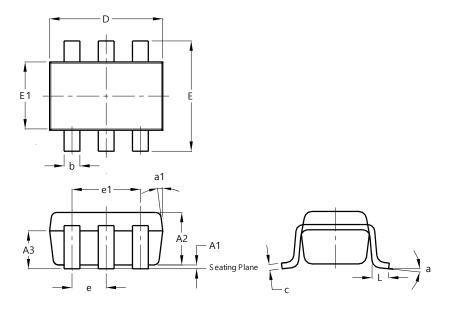




# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### SOT26

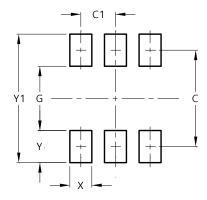


SOT26						
Dim	Min	Max	Тур			
A1	0.013	0.10	0.05			
A2	1.00	1.30	1.10			
A3	0.70	0.80	0.75			
b	0.35	0.50	0.38			
С	0.10	0.20	0.15			
D	2.90	3.10	3.00			
е	-	-	0.95			
e1	-	1	1.90			
Е	2.70	3.00	2.80			
E1	1.50	1.70	1.60			
L	0.35	0.55	0.40			
а	-	-	8°			
a1	-	-	7°			
All	Dimen	sions	in mm			

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### SOT26



Dimensions	Value (in mm)
С	2.40
C1	0.95
G	1.60
Х	0.55
Y	0.80
V1	3.20



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